

## **Application Data Sheet**

### **Application Information**

|   |  |
|---|--|
| <b>Application Type::</b>               | Regular  |
| <b>Subject Matter::</b>                 | Utility  |
| <b>Suggested classification::</b>       |  |
| <b>Suggested Group Art Unit::</b>       |  |
| <b>CD-ROM or CD-R?::</b>                | None   |
| <b>Computer Readable Form (CRF)?::</b>  | No   |
| <b>Title::</b>                          | SEMICONDUCTOR DEVICE INCLUDING<br>MOS FIELD EFFECT TRANSISTOR<br>HAVING OFFSET SPACERS OR GATE<br>SIDEWALL FILMS ON EITHER SIDE OF<br>GATE ELECTRODE AND METHOD OF<br>MANUFACTURING THE SAME |
| <b>Attorney Docket Number::</b>         | 016907-1577  |
| <b>Request for Early Publication?::</b> | No   |
| <b>Request for Non-Publication?::</b>   | No   |
| <b>Suggested Drawing Figure::</b>       |  |
| <b>Total Drawing Sheets::</b>           | 6  |
| <b>Small Entity?::</b>                  | No   |
| <b>Petition included?::</b>             | No   |
| <b>Secrecy Order in Parent Appl.?::</b> | No   |

### **Applicant Information**

|                                      |               |
|--------------------------------------|---------------|
| <b>Applicant Authority Type::</b>    | Inventor      |
| <b>Primary Citizenship Country::</b> | Japan         |
| <b>Status::</b>                      | Full Capacity |
| <b>Given Name::</b>                  | Hitoshi       |
| <b>Family Name::</b>                 | TSUNO         |

**City of Residence::** Yokohama-shi  
**Country of Residence::** Japan  
**Street of mailing address::** c/o TOSHIBA CORPORATION  
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Minato-ku, Tokyo 105-8001  
**Country of mailing address::** Japan

**Correspondence Information**

**Correspondence Customer Number::** 22428  
**E-Mail address::** PTOMailWashington@FoleyLaw.com

**Representative Information**

|   |       |  |
|---|-------|--|
| <b>Representative Customer Number::</b> | 22428 |  |
|---|-------|--|

**Domestic Priority Information**

|                      |                          |                             |                             |
|----------------------|--------------------------|-----------------------------|-----------------------------|
| <b>Application::</b> | <b>Continuity Type::</b> | <b>Parent Application::</b> | <b>Parent Filing Date::</b> |
|                      |                          |                             |                             |

**Foreign Priority Information**

|                  |                             |                      |                           |
|------------------|-----------------------------|----------------------|---------------------------|
| <b>Country::</b> | <b>Application number::</b> | <b>Filing Date::</b> | <b>Priority Claimed::</b> |
| Japan            | 2003-091972                 | 03/28/2003           | Yes                       |

**Assignee Information**

**Assignee name::** KABUSHIKI KAISHA TOSHIBA